TS5A23166
0.9-Ω DUAL SPST ANALOG SWITCH
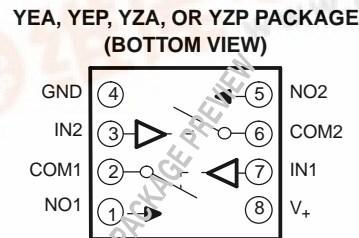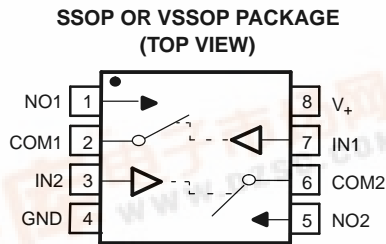## 5-V/3.3-V 2-CHANNEL ANALOG SWITCH

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FEATURES

- **Isolation in Powered-Down Mode, $V_+ = 0$**
- **Low ON-State Resistance (0.9 Ω)**
- **Control Inputs Are 5.5-V Tolerant**
- **Low Charge Injection**
- **Excellent ON-State Resistance Matching**
- **Low Total Harmonic Distortion (THD)**
- **1.65-V to 5.5-V Single-Supply Operation**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **ESD Performance Tested Per JESD 22**
  - – **2000-V Human-Body Model (A114-B, Class II)**
  - – **1000-V Charged-Device Model (C101)**

APPLICATIONS

- **Cell Phones**
- **PDAs**
- **Portable Instrumentation**
- **Audio and Video Signal Routing**
- **Low-Voltage Data-Acquisition Systems**
- **Communication Circuits**
- **Modems**
- **Hard Drives**
- **Computer Peripherals**
- **Wireless Terminals and Peripherals**

SSOP OR VSSOP PACKAGE (TOP VIEW)

NO1	1	8	V+
COM1	2	7	IN1
IN2	3	6	COM2
GND	4	5	NO2

YEA, YEP, YZA, OR YZP PACKAGE (BOTTOM VIEW)

GND	4	5	NO2
IN2	3	6	COM2
COM1	2	7	IN1
NO1	1	8	V+

DESCRIPTION/ORDERING INFORMATION

The TS5A23166 is a dual single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and an excellent channel-to-channel ON-state resistance matching. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

ORDERING INFORMATION

T_A	PACKAGE[1]		ORDERABLE PART NUMBER	TOP-SIDE MARKING[2]
−40°C to 85°C	NanoStar™ − WCSP (DSBGA) 0.23-mm Large Bump − YEP	Tape and reel	TS5A23166YEPR	PACKAGE PREVIEW
	NanoFree™ − WCSP (DSBGA) 0.23-mm Large Bump − YZP (Pb-free)		TS5A23166YZPR	PACKAGE PREVIEW
	SSOP − DCT	Tape and reel	TS5A23166DCTR	PACKAGE PREVIEW
	VSSOP − DCU (Pb-free)	Tape and reel	TS5A23166DCUR	JAM_

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.
   DCU: The actual top-side marking has one additional character that designates the assembly/test site.
   YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

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5-V/3.3-V 2-CHANNEL ANALOG SWITCH

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SUMMARY OF CHARACTERISTICS[1]

Configuration	Dual Single Pole, Single Throw (2 × SPST)
Number of channels	2
ON-state resistance (r_{on})	0.9 Ω
ON-state resistance match (Δr_{on})	0.1 Ω
ON-state resistance flatness ($r_{on(flat)}$)	0.25 Ω
Turn-on/turn-off time (t_{ON}/t_{OFF})	7.5 ns/9 ns
Charge injection (Q_C)	6 pC
Bandwidth (BW)	150 MHz
OFF isolation (O_{ISO})	−62 dB at 1 MHz
Crosstalk (X_{TALK})	−85 dB at 1 MHz
Total harmonic distortion (THD)	0.005%
Leakage current ($I_{COM(OFF)}$)	±20 nA
Power-supply current (I_+)	0.1 µA
Package option	8-pin VSSOP

(1) V_+ = 5 V, T_A = 25°C

FUNCTION TABLE

IN	NO TO COM, COM TO NO
L	OFF
H	ON

Absolute Maximum Ratings[1][2]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_+	Supply voltage range[3]		−0.5	6.5	V
V_{NO} V_{COM}	Analog voltage range[3][4][5]		−0.5	V_+ + 0.5	V
I_K	Analog port diode current	V_{NO}, V_{COM} < 0	−50		mA
I_{NO} I_{COM}	On-state switch current	V_{NO}, V_{COM} = 0 to V_+	−200	200	mA
	On-state peak switch current[6]		−400	400	
V_I	Digital input voltage range[3][4]		−0.5	6.5	V
I_{IK}	Digital input clamp current	V_I < 0	−50		mA
I_+	Continuous current through V_+			100	mA
I_{GND}	Continuous current through GND		−100	100	mA
θ_{JA}	Package thermal impedance[7]	DCT package		220	°C/W
		DCU package		227	
		YEA/YZA package		140	
		YEP/YZP package		102	
T_{stg}	Storage temperature range		−65	150	°C

(1)   Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3)   All voltages are with respect to ground, unless otherwise specified.
(4)   The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(5)   This value is limited to 5.5 V maximum.
(6)   Pulse at 1-ms duration < 10% duty cycle.
(7)   The package thermal impedance is calculated in accordance with JESD 51-7.

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Electrical Characteristics for 5-V Supply[1]

V_+ = 4.5 V to 5.5 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, I_{COM} = –100 mA,	Switch ON, See Figure 13	25°C	4.5 V		0.9	1.1	Ω
				Full				1.2	
ON-state resistance	r_{on}	V_{NO} = 2.5 V, I_{COM} = –100 mA,	Switch ON, See Figure 13	25°C	4.5 V		0.75	0.9	Ω
				Full				1	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 2.5 V, I_{COM} = –100 mA,	Switch ON, See Figure 13	25°C	4.5 V		0.04	0.1	Ω
				Full				0.1	
ON-state resistance flatness	$r_{on(flat)}$	$0 \leq V_{NO} \leq V_+$, I_{COM} = –100 mA,	Switch ON, See Figure 13	25°C	4.5 V		0.2		Ω
		V_{NO} = 1 V, 1.5 V, 2.5 V, I_{COM} = –100 mA,	Switch ON, See Figure 13	25°C			0.15	0.25	
				Full				0.25	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 1 V, V_{COM} = 4.5 V, or V_{NO} = 4.5 V, V_{COM} = 1 V,	Switch OFF, See Figure 14	25°C	5.5 V	0 V	4	20	nA
				Full		–150		150	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 5.5 V, V_{COM} = 5.5 V to 0,	Switch OFF, See Figure 14	25°C	0 V	–10	0.2	10	μA
				Full		–50		50	
COM OFF leakage current	$I_{COM(OFF)}$	V_{COM} = 1 V, V_{NO} = 4.5 V, or V_{COM} = 4.5 V, V_{NO} = 1 V,	Switch OFF, See Figure 14	25°C	5.5 V	0 V	4	20	nA
				Full		–150		150	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 5.5 V, V_{NO} = 5.5 V to 0,	Switch OFF, See Figure 14	25°C	0 V	–10	0.2	10	μA
				Full		–50		50	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 1 V, V_{COM} = Open, or V_{NO} = 4.5 V, V_{COM} = Open,	Switch ON, See Figure 15	25°C	5.5 V	–5	0.4	5	nA
				Full		–50		50	
COM ON leakage current	$I_{COM(ON)}$	V_{COM} = 1 V, V_{NO} = Open, or V_{COM} = 4.5 V, V_{NO} = Open,	Switch ON, See Figure 15	25°C	5.5 V	–5	0.4	5	nA
				Full		–50		50	
Digital Control Inputs (IN1, IN2)[2]									
Input logic high	V_{IH}			Full		2.4		5.5	V
Input logic low	V_{IL}			Full		0		0.8	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	5.5 V	–2	0.3	2	nA
				Full		–20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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Electrical Characteristics for 5-V Supply[1] (continued)

V_+ = 4.5 V to 5.5 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, $R_L = 50\,\Omega$,	C_L= 35 pF, See Figure 17	25°C	5 V	1	4.5	7.5	ns
				Full	4.5 V to 5.5 V	1		9	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, $R_L = 50\,\Omega$,	C_L = 35 pF, See Figure 17	25°C	5 V	4.5	8	11	ns
				Full	4.5 V to 5.5 V	3.5		13	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$,	C_L = 1 nF, See Figure 21	25°C	5 V		6		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	5 V		19		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	5 V		18		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	See Figure 16	25°C	5 V		35.5		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	See Figure 16	25°C	5 V		35.5		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 16	25°C	5 V		2		pF
Bandwidth	BW	$R_L = 50\,\Omega$, Switch ON,	See Figure 18	25°C	5 V		150		MHz
OFF isolation	O_{ISO}	$R_L = 50\,\Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	5 V		−62		dB
Crosstalk	X_{TALK}	$R_L = 50\,\Omega$, f = 1 MHz,	Switch ON, See Figure 20	25°C	5 V		−85		dB
Total harmonic distortion	THD	$R_L = 600\,\Omega$, $C_L = 50$ pF,	f = 20 Hz to 20 kHz, See Figure 22	25°C	5 V		0.005		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	5.5 V		0.01	0.1	μA
				Full				1	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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Electrical Characteristics for 3.3-V Supply[1]

V_+ = 4.5 V to 5.5 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, I_{COM} = −100 mA,	Switch ON, See Figure 13	25°C	3 V		1.3	1.6	Ω
				Full				1.8	
ON-state resistance	r_{on}	V_{NO} = 2 V, I_{COM} = −100 mA,	Switch ON, See Figure 13	25°C	3 V		1.1	1.5	Ω
				Full				1.7	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 2 V, 0.8 V, I_{COM} = −100 mA,	Switch ON, See Figure 13	25°C	3 V		0.04	0.1	Ω
				Full				0.1	
ON-state resistance flatness	$r_{on(flat)}$	$0 \leq V_{NO} \leq V_+$, I_{COM} = −100 mA	Switch ON, See Figure 13	25°C	3 V		0.3		Ω
		V_{NO} = 2 V, 0.8 V, I_{COM} = −100 mA,	Switch ON, See Figure 13	25°C			0.15	0.25	
				Full				0.25	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 1 V, V_{COM} = 3 V, or V_{NO} = 3 V, V_{COM} = 1 V,	Switch OFF, See Figure 14	25°C	3.6 V	−5	0.5	5	nA
				Full		−50		50	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 3.6 V, V_{COM} = 3.6 V to 0,	Switch OFF, See Figure 14	25°C	0 V	−5	0.1	5	µA
				Full		−25		25	
COM OFF leakage current	$I_{COM(OFF)}$	V_{COM} = 1 V, V_{NO} = 3 V, or V_{COM} = 3 V, V_{NO} = 1 V,	Switch OFF, See Figure 14	25°C	3.6 V	−5	0.5	5	nA
				Full		−50		50	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 3.6 V, V_{NO} = 3.6 V to 0,	Switch OFF, See Figure 14	25°C	0 V	−5	0.1	5	µA
				Full		−25		25	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 1 V, V_{COM} = Open, or V_{NO} = 3 V, V_{COM} = Open,	Switch ON, See Figure 15	25°C	3.6 V	−2	0.3	2	nA
				Full		−20		20	
COM ON leakage current	$I_{COM(ON)}$	V_{COM} = 1 V, V_{NO} = Open, or V_{COM} = 3 V, V_{NO} = Open,	Switch ON, See Figure 15	25°C	3.6 V	−2	0.3	2	nA
				Full		−20		20	
Digital Control Inputs (IN1, IN2)[2]									
Input logic high	V_{IH}			Full		2		5.5	V
Input logic low	V_{IL}			Full		0		0.8	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	3.6 V	−2	0.3	2	nA
				Full		−20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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Electrical Characteristics for 3.3-V Supply[1] (continued)

V_+ = 4.5 V to 5.5 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L= 35 pF, See Figure 17	25°C	3.3 V	1.5	5	9.5	ns
				Full	3 V to 3.6 V	1		10	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 17	25°C	3.3 V	4.5	8.5	11	ns
				Full	3 V to 3.6 V	3		12.5	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 21	25°C	5 V			6	pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	3.3 V			19.5	pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	3.3 V			18.5	pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	See Figure 16	25°C	3.3 V			36	pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	See Figure 16	25°C	3.3 V			36	pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 16	25°C	3.3 V			2	pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	3.3 V			150	MHz
OFF isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch OFF, See Figure 19	25°C	3.3 V			−62	dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz,	Switch ON, See Figure 20	25°C	3.3 V			−85	dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 22	25°C	3.3 V			0.01	%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	3.6 V		0.001	0.05	µA
				Full				0.3	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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Electrical Characteristics for 2.5-V Supply[(1)]

V_+ = 2.3 V to 2.7 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, I_{COM} = –8 mA,	Switch ON, See Figure 13	25°C	2.3 V		1.8	2.4	Ω
				Full				2.6	
ON-state resistance	r_{on}	V_{NO} = 1.8 V, I_{COM} = –8 mA,	Switch ON, See Figure 13	25°C	2.3 V		1.2	2.1	Ω
				Full				2.4	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 1.8 V, 0.8 V, I_{COM} = –8 mA,	Switch ON, See Figure 13	25°C	2.3 V		0.04	0.15	Ω
				Full				0.15	
ON-state resistance flatness	$r_{on\ (flat)}$	$0 \leq V_{NO} \leq V_+$, I_{COM} = –8 mA,	Switch ON, See Figure 13	25°C	2.3 V		0.7		Ω
		V_{NO} = 1.8 V, 0.8 V, I_{COM} = –8 mA,	Switch ON, See Figure 13	25°C			0.4	0.6	
				Full				0.6	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 0.5 V, V_{COM} = 2.3 V, or V_{NO} = 2.3 V, V_{COM} = 0.5 V,	Switch OFF, See Figure 14	25°C	2.7 V	–5	0.3	5	nA
				Full		–50		50	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 2.7 V, V_{COM} = 2.7 V to 0,	Switch OFF, See Figure 14	25°C	0 V	–2	0.05	2	µA
				Full		–15		15	
COM OFF leakage current	$I_{COM(OFF)}$	V_{NO} = 2.3 V, V_{COM} = 0.5 V, or V_{NO} = 0.5 V, V_{COM} = 2.3 V,	Switch OFF, See Figure 14	25°C	2.7 V	–5	0.3	5	nA
				Full		–50		50	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 2.7 V, V_{NO} = 2.7 V to 0,	Switch OFF, See Figure 14	25°C	0 V	–2	0.05	2	µA
				Full		–15		15	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 0.5 V, V_{COM} = Open, or V_{NO} = 2.3 V, V_{COM} = Open,	Switch ON, See Figure 15	25°C	2.7 V	–2	0.3	2	nA
				Full		–20		20	
COM ON leakage current	$I_{COM(ON)}$	V_{COM} = 0.5 V, V_{NO} = Open, or V_{COM} = 2.3 V, V_{NO} = Open,	Switch ON, See Figure 15	25°C	2.7 V	–2	0.3	2	nA
				Full		–20		20	
Digital Control Inputs (IN1, IN2)									
Input logic high	V_{IH}			Full		1.8		5.5	V
Input logic low	V_{IL}			Full		0		0.6	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	2.7 V	–2	0.3	2	nA
				Full		–20		20	

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

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Electrical Characteristics for 2.5-V Supply[1] (continued)

V_+ = 2.3 V to 2.7 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 17	25°C	2.5 V	2	6	10	ns
				Full	2.3 V to 2.7 V	1		12	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 17	25°C	2.5 V	4.5	8	12.5	ns
				Full	2.3 V to 2.7 V	3		15	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 21	25°C	2.5 V		4		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		19.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		18.5		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	See Figure 16	25°C	2.5 V		36.5		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	See Figure 16	25°C	2.5 V		36.5		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 16	25°C	2.5 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	2.5 V		150		MHz
OFF isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch OFF, See Figure 19	25°C	2.5 V		−62		dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz,	Switch ON, See Figure 20	25°C	2.5 V		−85		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 22	25°C	2.5 V		0.02		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	2.7 V		0.001	0.02	μA
				Full				0.25	

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

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0.9-Ω DUAL SPST ANALOG SWITCH
5-V/3.3-V 2-CHANNEL ANALOG SWITCH

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Electrical Characteristics for 1.8-V Supply[1]

V_+ = 1.65 V to 1.95 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}					0		V_+	V
Peak ON resistance	r_{peak}	$0 \leq V_{NO} \leq V_+$, I_{COM} = −2 mA,	Switch ON, See Figure 13	25°C	1.65 V		4.2	25	Ω
				Full				30	
ON-state resistance	r_{on}	V_{NO} = 0.6 V, 1.5 V, I_{COM} = −2 mA,	Switch ON, See Figure 13	25°C	1.65 V		1.6	3.9	Ω
				Full				4	
ON-state resistance match between channels	Δr_{on}	V_{NO} = 1.5 V, I_{COM} = −2 mA,	Switch ON, See Figure 13	25°C	1.65 V		0.04	0.2	Ω
				Full				0.2	
ON-state resistance flatness	$r_{on\ (flat)}$	$0 \leq V_{NO} \leq V_+$, I_{COM} = −2 mA,	Switch ON, See Figure 13	25°C	1.65 V		2.8		Ω
		V_{NO} = 0.6 V, 1.5 V, I_{COM} = −2 mA,	Switch ON, See Figure 13	25°C			4.1	22	
				Full				27	
NO OFF leakage current	$I_{NO(OFF)}$	V_{NO} = 0.3 V, V_{COM} = 1.65 V, or V_{NO} = 1.65 V, V_{COM} = 0.3 V,	Switch OFF, See Figure 14	25°C	1.95 V	−5	0.3	5	nA
				Full		−50		50	
	$I_{NO(PWROFF)}$	V_{NO} = 0 to 1.95 V, V_{COM} = 1.95 V to 0,	Switch OFF, See Figure 14	25°C	0 V	−2	0.05	2	μA
				Full		−10		10	
COM OFF leakage current	$I_{COM(OFF)}$	V_{NO} = 1.65 V, V_{COM} = 0.3 V, or V_{NO} = 0.3 V, V_{COM} = 1.65 V,	Switch OFF, See Figure 14	25°C	1.95 V	−5	0.3	5	nA
				Full		−50		50	
	$I_{COM(PWROFF)}$	V_{COM} = 0 to 1.95 V, V_{NO} = 1.95 V to 0,	Switch OFF, See Figure 14	25°C	0 V	−2	0.05	2	μA
				Full		−10		10	
NO ON leakage current	$I_{NO(ON)}$	V_{NO} = 0.3 V, V_{COM} = Open, or V_{NO} = 1.65 V, V_{COM} = Open,	Switch ON, See Figure 15	25°C	1.95 V	−2	0.3	2	nA
				Full		−20		20	
COM ON leakage current	$I_{COM(ON)}$	V_{NO} = Open, V_{COM} = 0.3 V, or V_{NO} = Open, V_{COM} = 1.65 V,	Switch ON, See Figure 15	25°C	1.95 V	−2	0.3	2	nA
				Full		−20		20	
Digital Control Inputs (IN1, IN2)									
Input logic high	V_{IH}			Full		1.5		5.5	V
Input logic low	V_{IL}			Full		0		0.6	V
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	1.95 V	−2	0.3	2	μA
				Full		−20		20	

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.
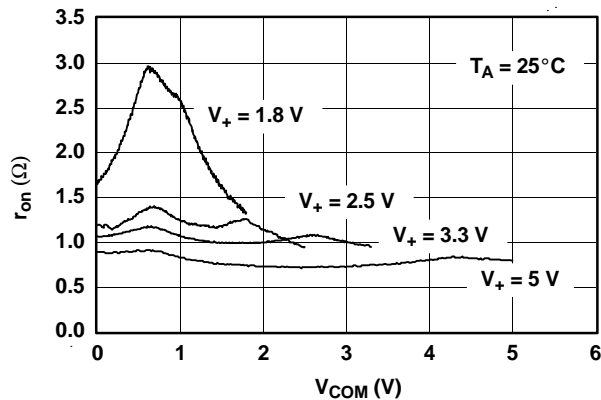
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Electrical Characteristics for 1.8-V Supply[1] (continued)

V_+ = 1.65 V to 1.95 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 17	25°C	1.8 V	3	9	18	ns
				Full	1.65 V to 1.95 V	1		20	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 17	25°C	1.8 V	5	10	15.5	ns
				Full	1.65 V to 1.95 V	4		18.5	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 21	25°C	1.8 V		2		pC
NO OFF capacitance	$C_{NO(OFF)}$	$V_{NO} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		19.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		18.5		pF
NO ON capacitance	$C_{NO(ON)}$	$V_{NO} = V_+$ or GND, Switch ON,	See Figure 16	25°C	1.8 V		36.5		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON,	See Figure 16	25°C	1.8 V		36.5		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 16	25°C	1.8 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	1.8 V		150		MHz
OFF isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch OFF, See Figure 19	25°C	1.8 V		–62		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 22	25°C	1.8 V		0.055		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch ON or OFF	25°C	1.95 V		0.001	0.01	μA
				Full				0.15	

(1) The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

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TYPICAL PERFORMANCE

Figure 1. r_{on} vs V_{COM}
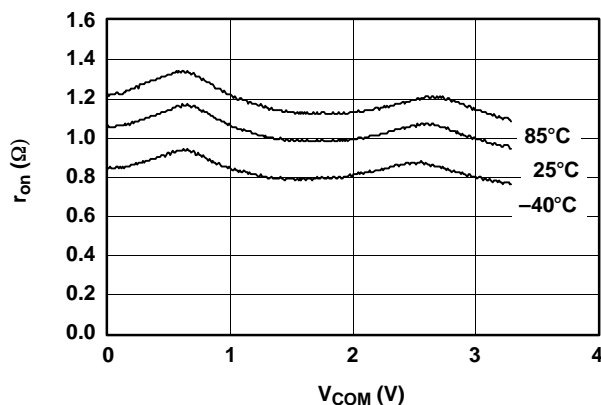
Figure 2. r_{on} vs V_{COM} (V_+ = 3.3 V)

Figure 3. r_{on} vs V_{COM} (V_+ = 5 V)

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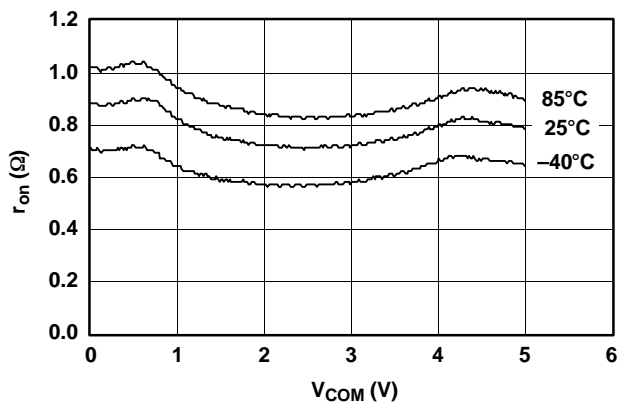
TYPICAL PERFORMANCE
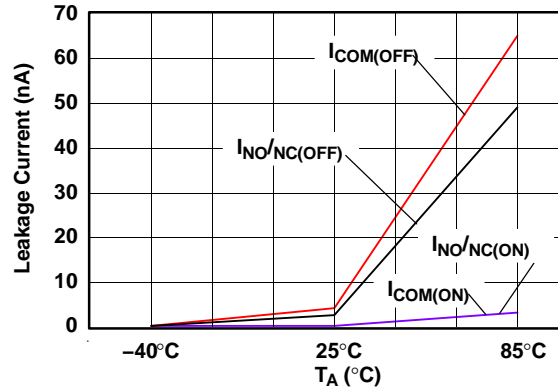
Figure 4. Leakage Current vs Temperature (V$_+$ = 5.5 V)
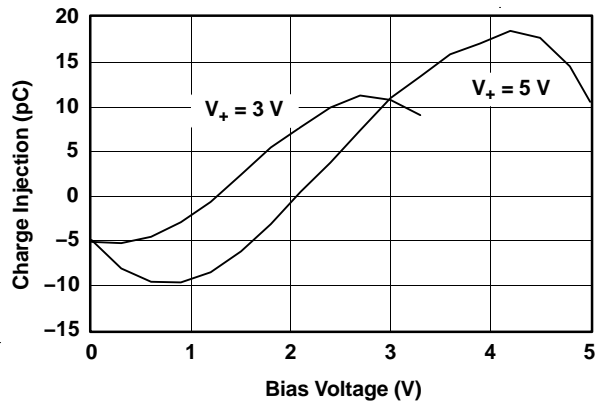
Figure 5. Charge Injection (Q$_C$) vs V$_{COM}$
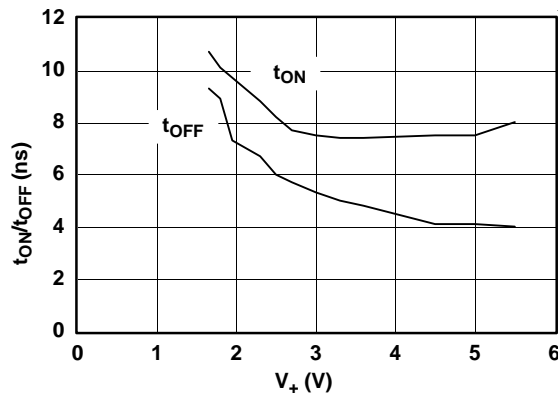
Figure 6. t$_{ON}$ and t$_{OFF}$ vs Supply Voltage

TYPICAL PERFORMANCE
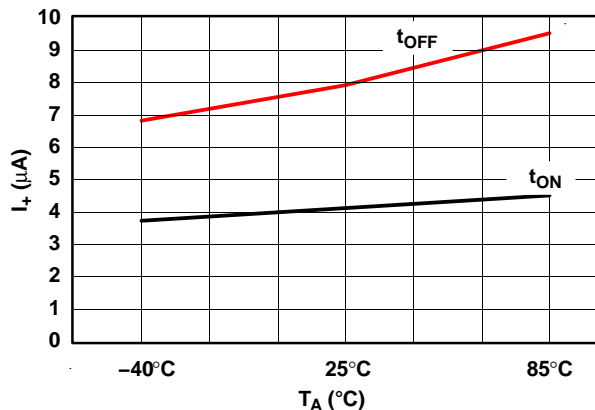
Figure 7. t_{ON} and t_{OFF} vs Temperature (V_+ = 5 V)
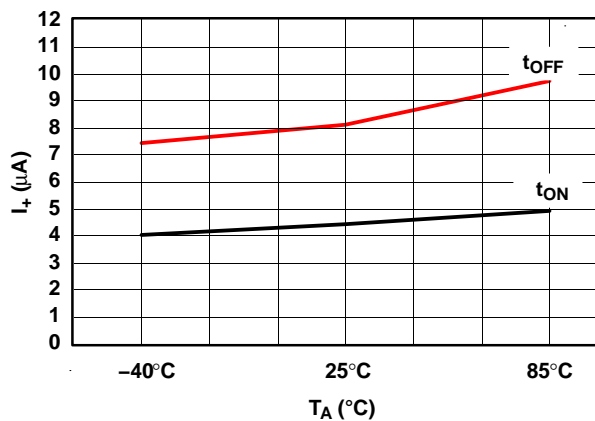
Figure 8. Logic-Level Theshold vs V_+

Figure 9. Bandwidth (V_+ = 5 V)

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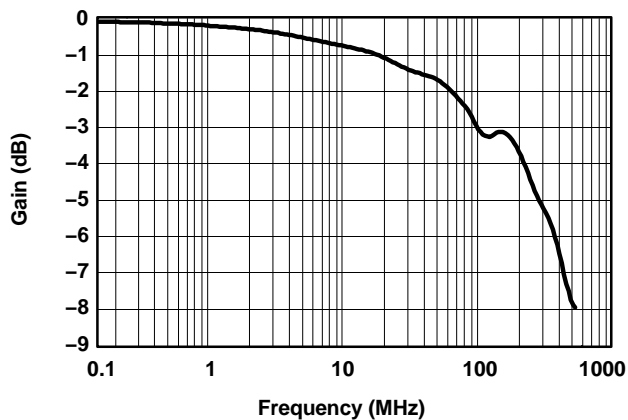
TYPICAL PERFORMANCE
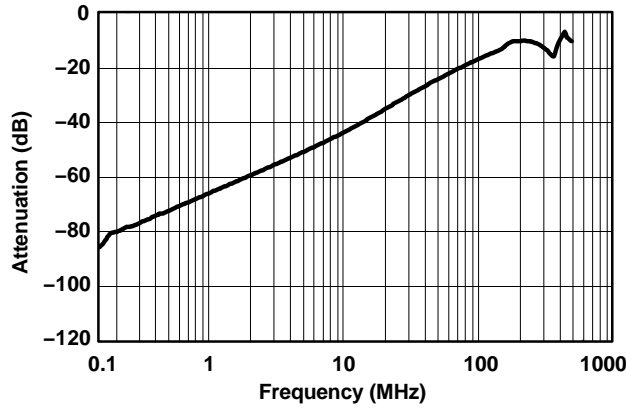
Figure 10. OFF Isolation and Crosstalk (V₊ = 5 V)
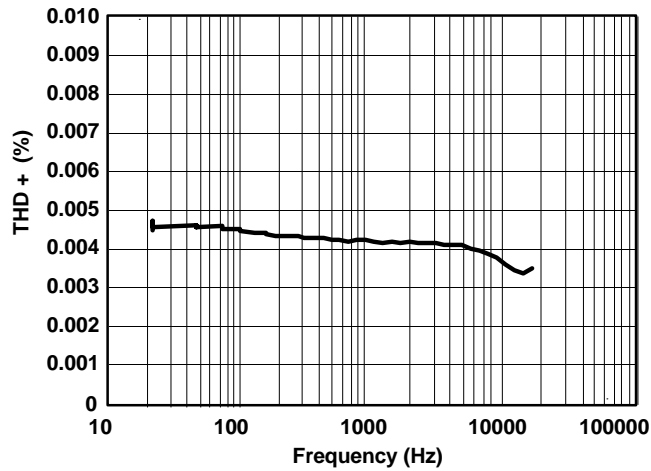
Figure 11. Total Harmonic Distortion vs Frequency
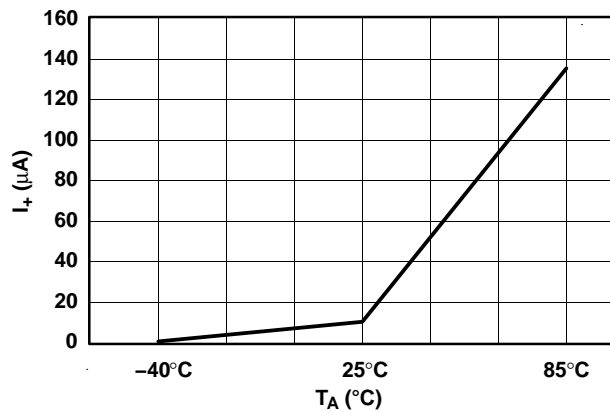
Figure 12. Power-Supply Current vs Temperature (V₊ = 5 V)

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PIN DESCRIPTION

PIN NUMBER	NAME	DESCRIPTION
1	NO1	Normally closed
2	COM1	Common
3	IN2	Digital control pin to connect COM to NO
4	GND	Digital ground
5	NO2	Normally closed
6	COM2	Common
7	IN1	Digital control pin to connect COM to NO
8	V$_+$	Power Supply

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V$_{COM}$	Voltage at COM
V$_{NO}$	Voltage at NO
r$_{on}$	Resistance between COM and NO ports when the channel is ON
r$_{on(flat)}$	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions
I$_{NO(OFF)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
I$_{NO(ON)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
I$_{COM(OFF)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the OFF state
I$_{COM(ON)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the ON state and the output (NO) open
V$_{IH}$	Minimum input voltage for logic high for the control input (IN)
V$_{IL}$	Maximum input voltage for logic low for the control input (IN)
V$_I$	Voltage at the control input (IN)
I$_{IH}$, I$_{IL}$	Leakage current measured at the control input (IN)
t$_{ON}$	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON.
t$_{OFF}$	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF.
Q$_C$	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$, C_L is the load capacitance and ΔV_{COM} is the change in analog output voltage.
C$_{NO(OFF)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
C$_{NO(ON)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
C$_{COM(OFF)}$	Capacitance at the COM port when the corresponding channel (COM to NO) is OFF
C$_{COM(ON)}$	Capacitance at the COM port when the corresponding channel (COM to NO) is ON
C$_I$	Capacitance of IN
O$_{ISO}$	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NO to COM) in the OFF state.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain.
THD	Total harmonic distortion is defined as the ratio of the root mean square (RMS) value of the second, third, and higher harmonics to the magnitude of fundamental harmonic.
I$_+$	Static power-supply current with the control (IN) pin at V$_+$ or GND
ΔI$_+$	This is the increase in I$_+$ for each control (IN) input that is at the specified voltage, rather than at V$_+$ or GND.

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PARAMETER MEASUREMENT INFORMATION

Channel ON

$$r_{on} = \frac{V_{COM} - V_{NO}}{I_{COM}} \; \Omega$$

$V_I = V_{IH}$ or V_{IL}
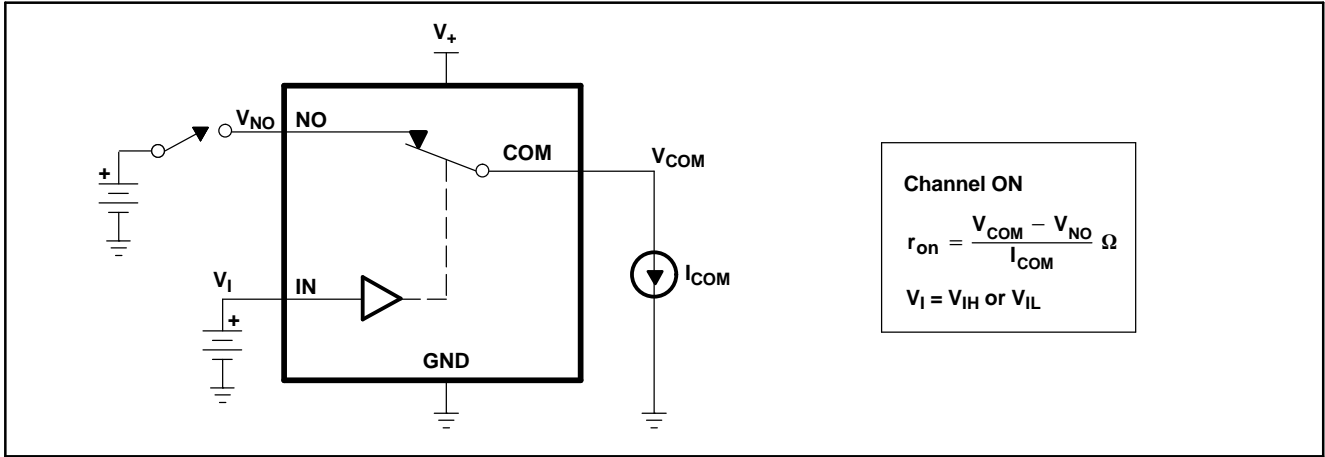
Figure 13. ON-State Resistance (r_{on})
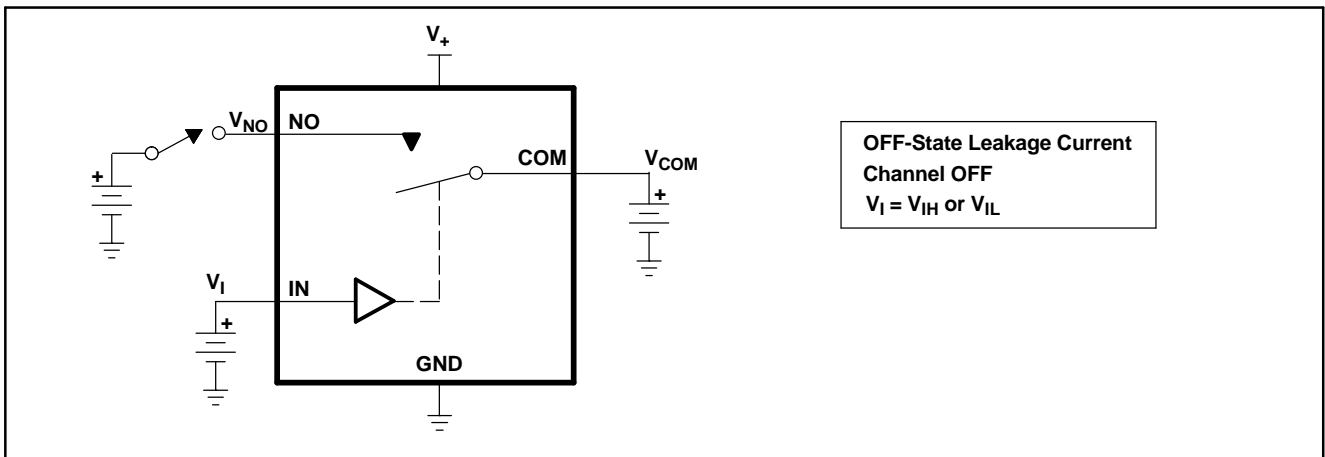

OFF-State Leakage Current
Channel OFF
$V_I = V_{IH}$ or V_{IL}

Figure 14. OFF-State Leakage Current ($I_{COM(OFF)}$, $I_{NC(OFF)}$, $I_{COM(PWROFF)}$, $I_{NC(PWR(FF)}$)

ON-State Leakage Current
Channel ON
$V_I = V_{IH}$ or V_{IL}
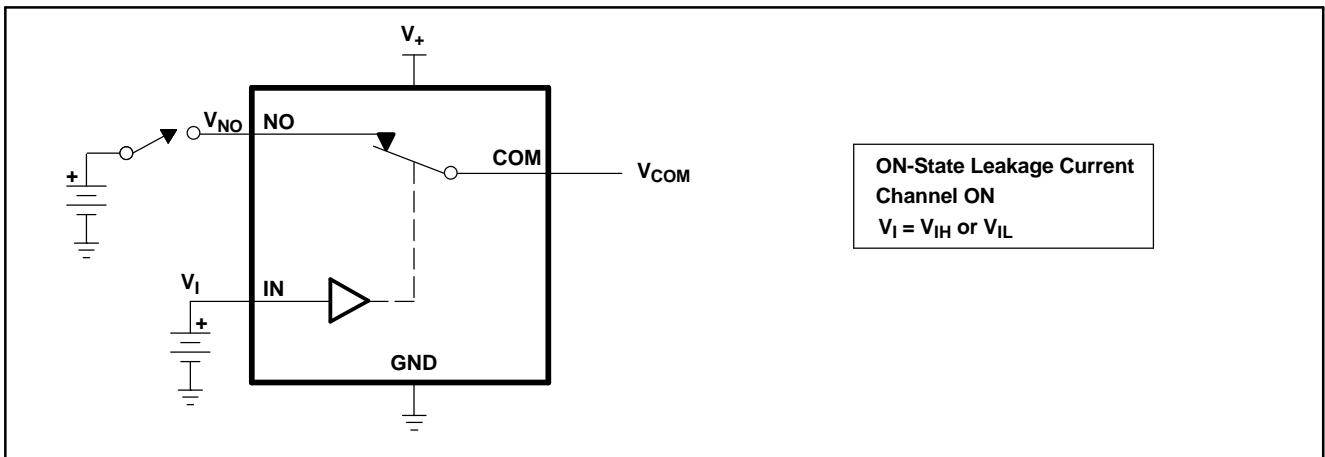
Figure 15. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$)
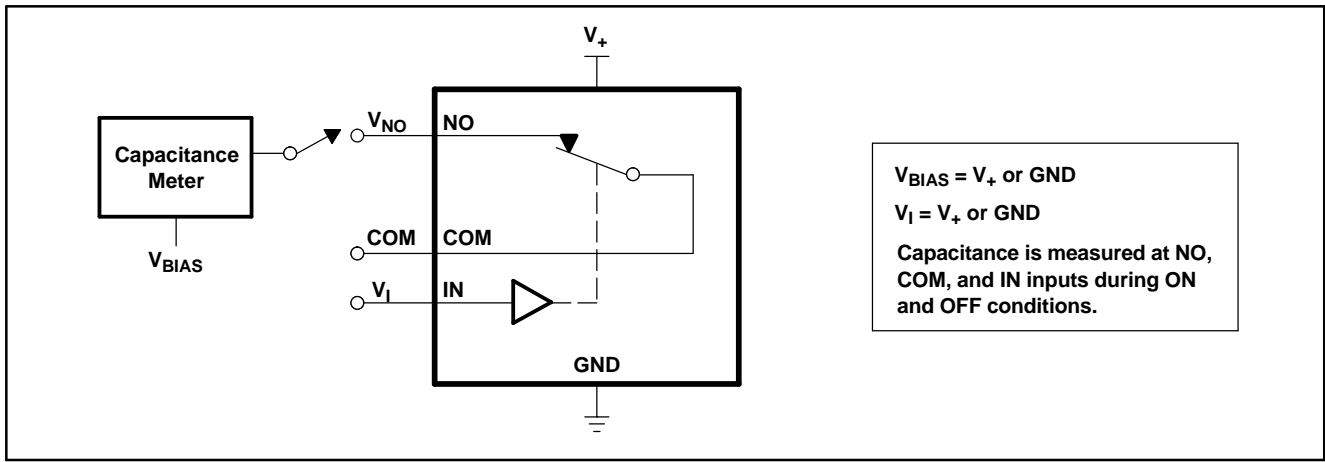
Figure 16. Capacitance (C_I, $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)

TEST	R_L	C_L	V_{COM}
t_{ON}	50 Ω	35 pF	V_+
t_{OFF}	50 Ω	35 pF	V_+
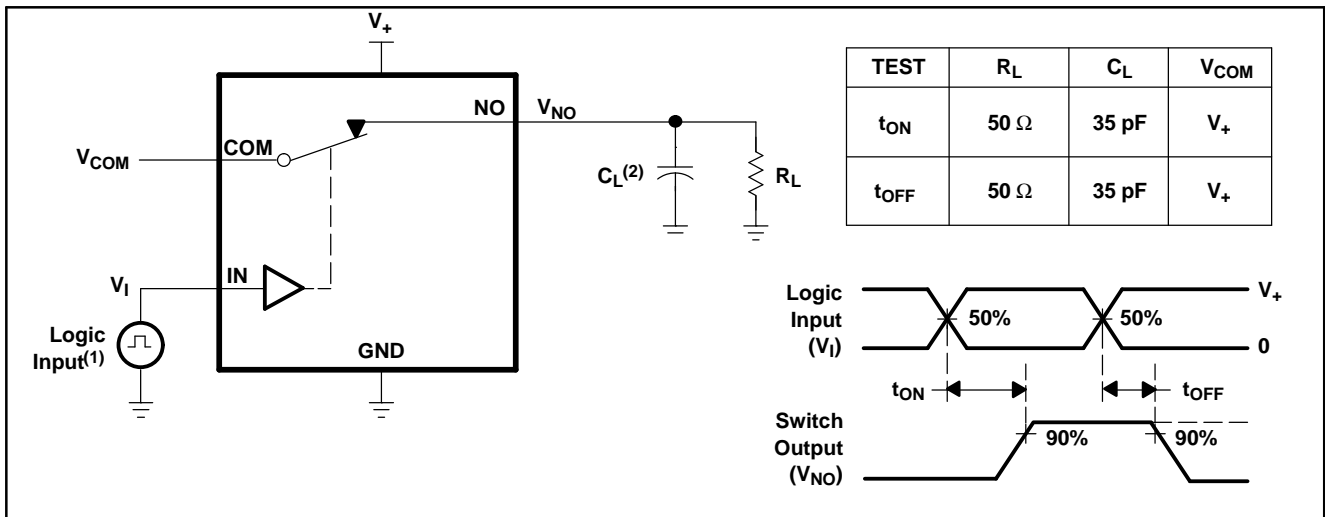
(1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.

(2) C_L includes probe and jig capacitance.

Figure 17. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

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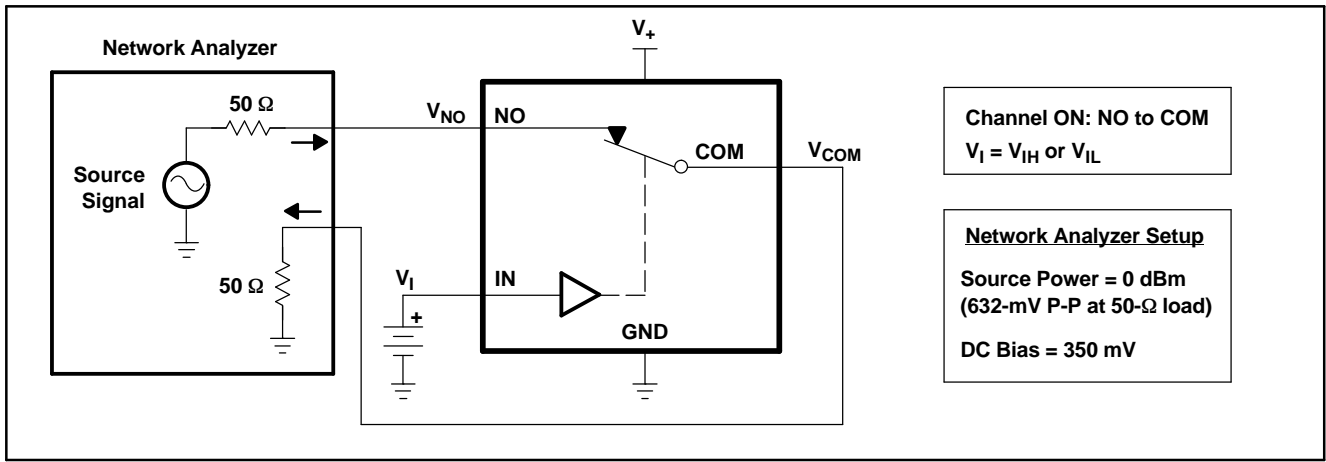
Figure 18. Bandwidth (BW)
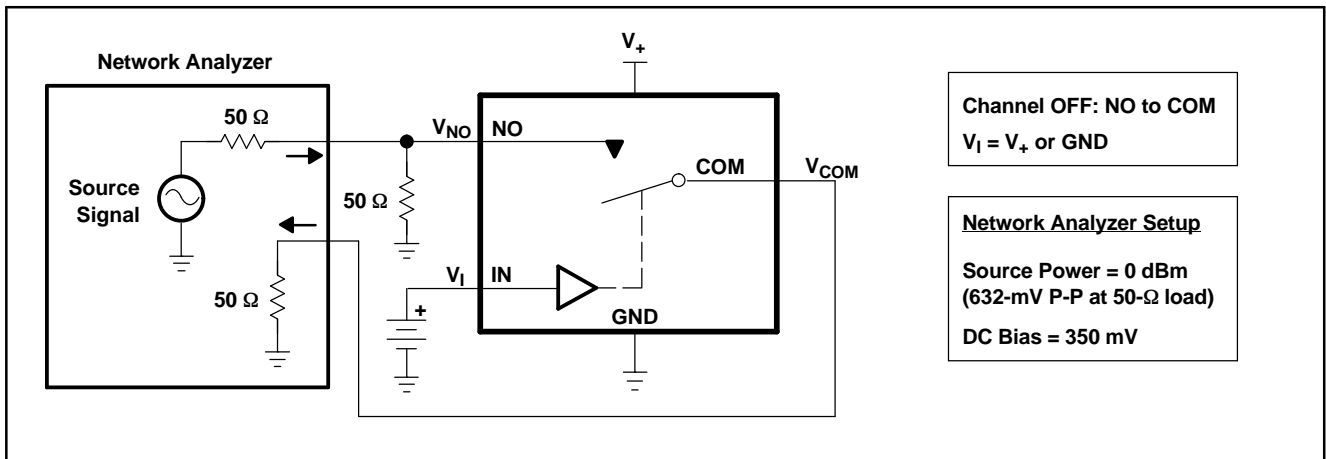
Figure 19. OFF Isolation (O$_{ISO}$)

Figure 20. Crosstalk (X$_{TALK}$)

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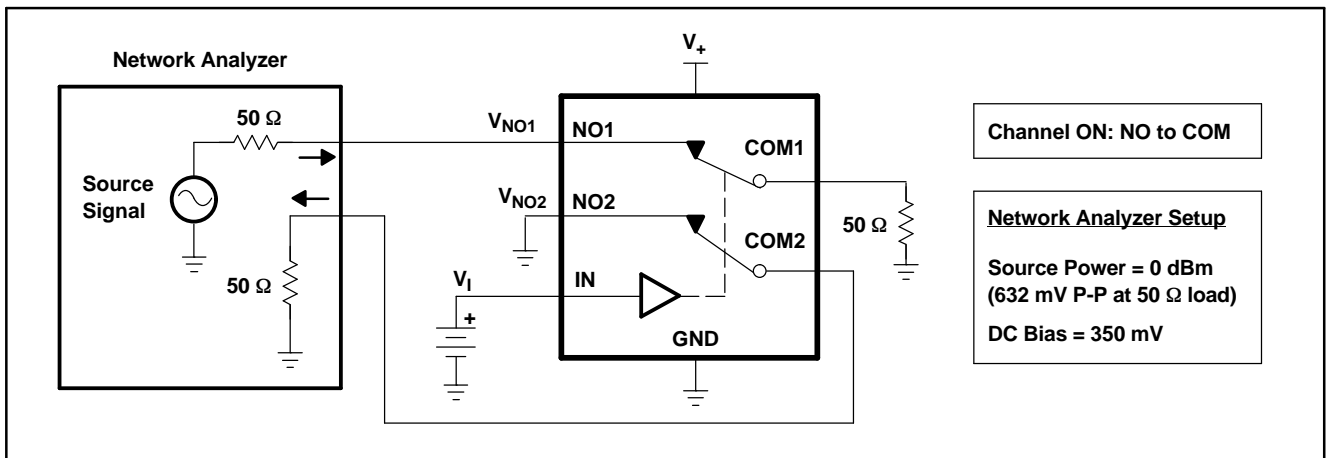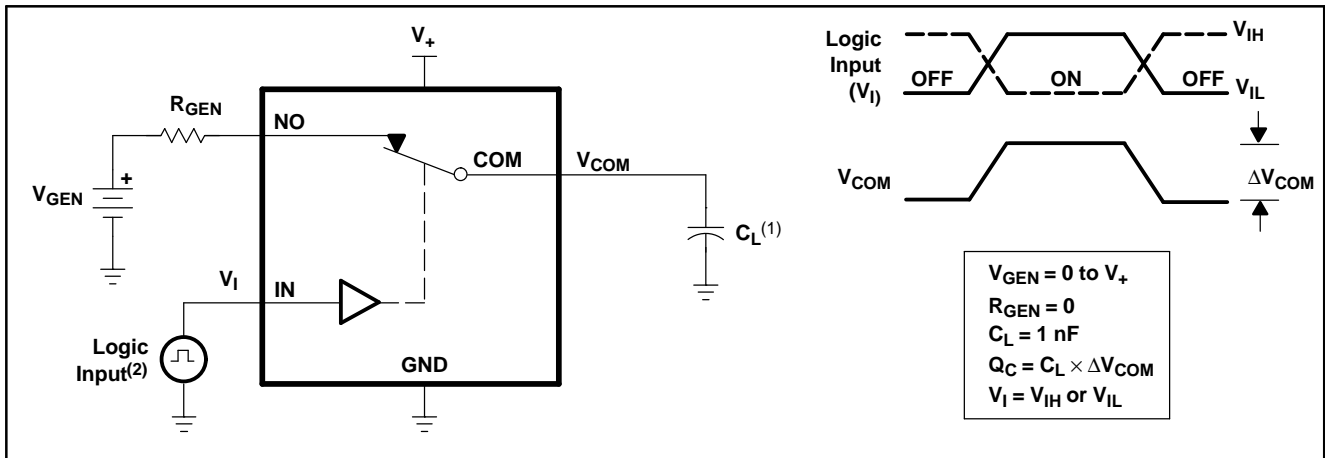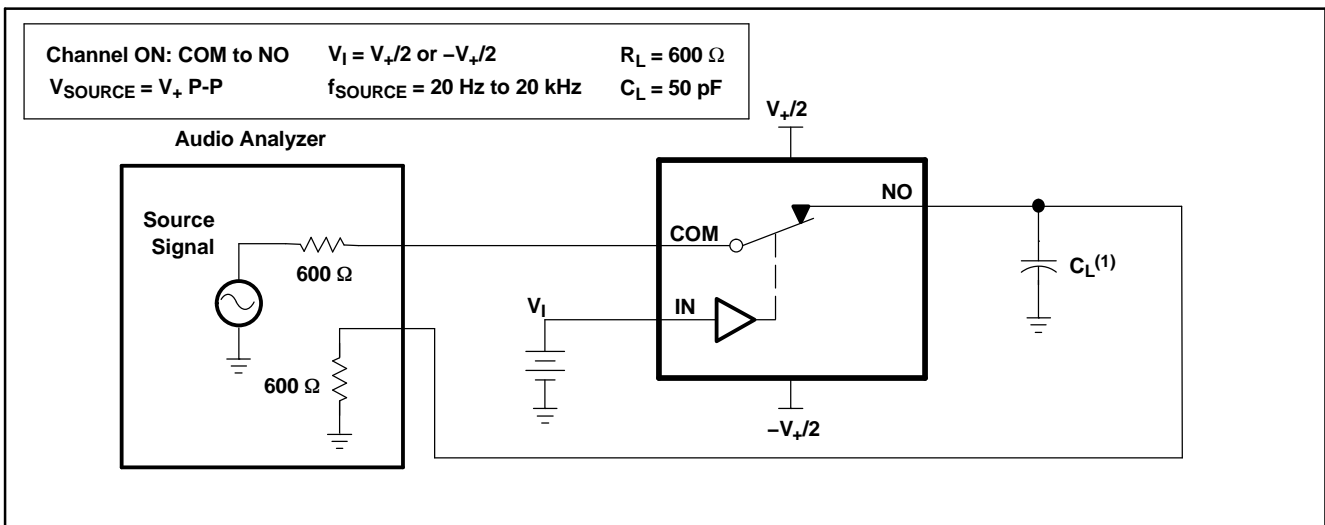**0.9-Ω DUAL SPST ANALOG SWITCH**
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(1) C_L includes probe and jig capacitance.
(2) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.

Figure 21. Charge Injection (Q_C)

(1) C_L includes probe and jig capacitance.

Figure 22. Total Harmonic Distortion (THD)

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
TS5A23166DCUR	ACTIVE	US8	DCU	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
TS5A23166DCURE4	ACTIVE	US8	DCU	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
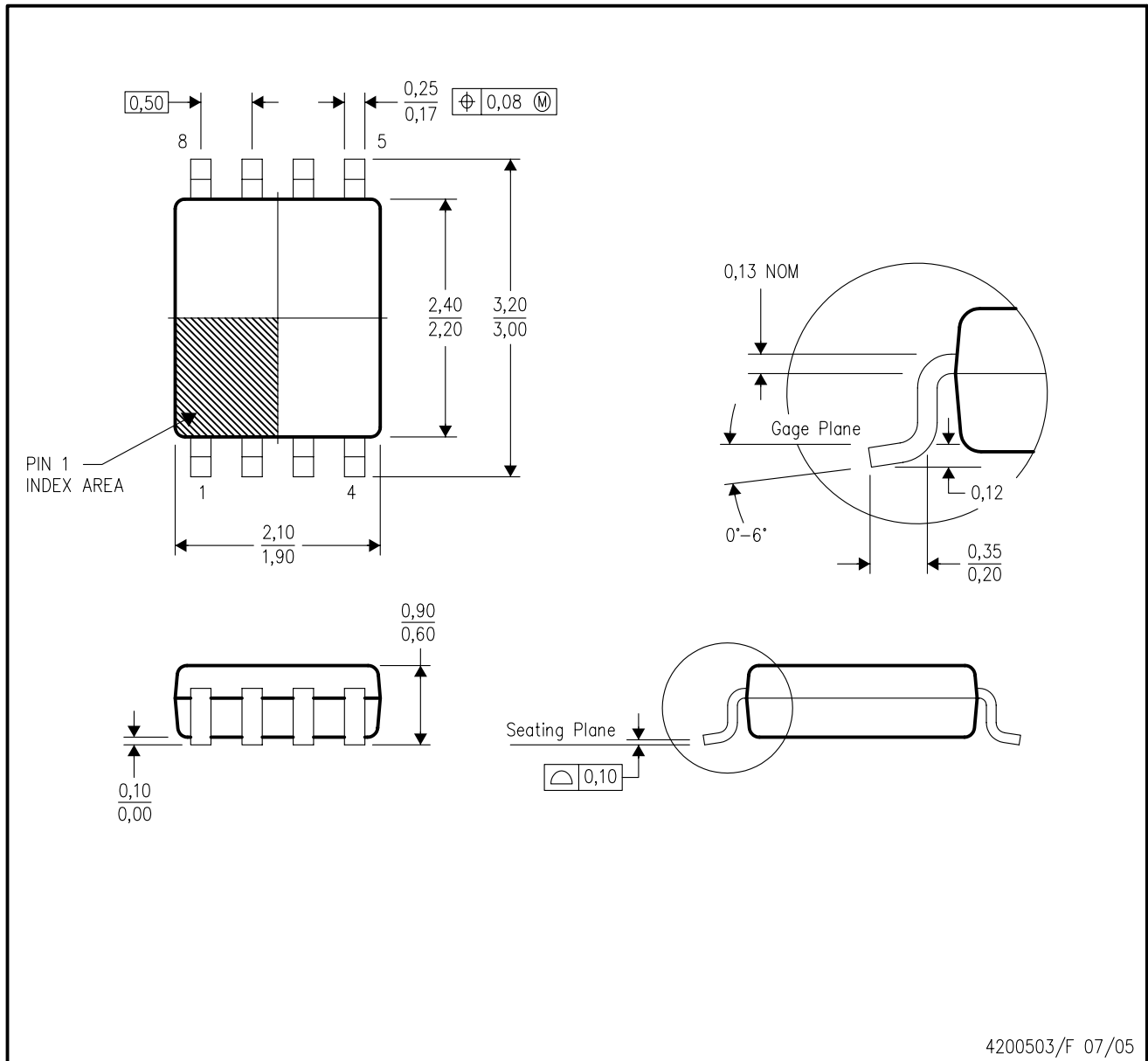
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DCU (R-PDSO-G8)   PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)

0,50

0,25 / 0,17   ⊕ 0,08 Ⓜ

8   5

2,40 / 2,20   3,20 / 3,00

PIN 1
INDEX AREA

1   4

2,10 / 1,90

0,13 NOM

Gage Plane

0°-6°

0,12

0,35 / 0,20

0,90 / 0,60

0,10 / 0,00

Seating Plane

⌒ 0,10

4200503/F 07/05

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
         D.   Falls within JEDEC MO-187 variation CA.

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